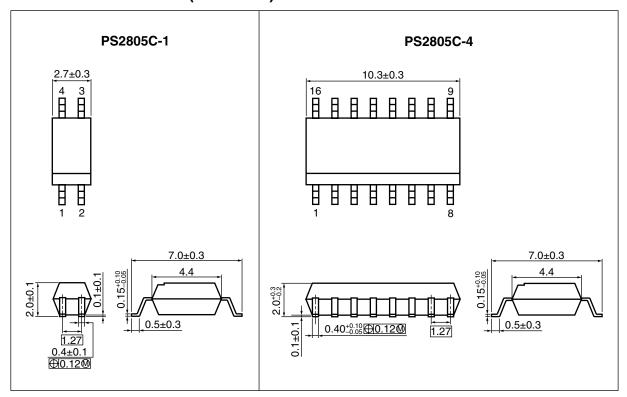
## PACKAGE DIMENSIONS (UNIT: mm)

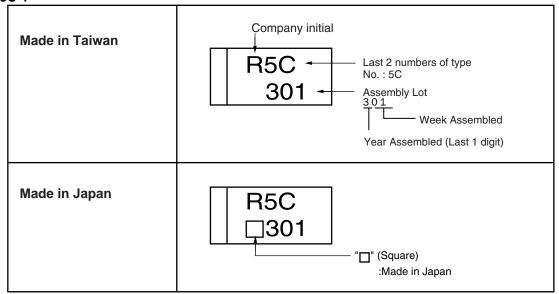


## <R> PHOTOCOUPLER CONSTRUCTION

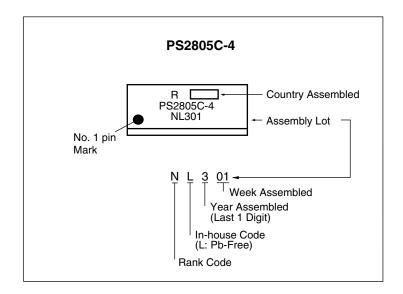
Parameter	Unit (MIN.)
Air Distance	4.5 mm
Outer Creepage Distance	4.5 mm
Inner Creepage Distance	2.5 mm
Isolation Distance	0.1 mm

### <R> MARKING EXAMPLE

### PS2805C-1



### PS2805C-4



### <R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standards Approval	Application Part Number <sup>*1</sup>
PS2805C-1-F3	PS2805C-1-F3-A	Pb-Free	Embossed Tape 3 500 pcs/reel	Standard products (UL, CSA, BSI approved)	PS2805C-1
PS2805C-4-F3	PS2805C-4-F3-A		Embossed Tape 2 500 pcs/reel		PS2805C-4
PS2805C-1-V-F3	PS2805C-1-V-F3-A		Embossed Tape 3 500 pcs/reel	DIN EN 60747-5-5 (VDE0884-5)	PS2805C-1
PS2805C-4-V-F3	PS2805C-4-V-F3-A		Embossed Tape 2 500 pcs/reel	Approved (Option)	PS2805C-4

Note: \*1. For the application of the Safety Standard, following part number should be used.

## ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ , unless otherwise specified)

	Parameter	Symbol	Rat	ings	Unit
			PS2805C-1	PS2805C-4	
Diode	Forward Current (DC)	I <sub>F</sub>	±:	30	mA/ch
	Power Dissipation Derating	⊿P <sub>D</sub> /°C	0.6	0.8	mW/°C
	Power Dissipation	P <sub>D</sub>	60	80	mW/ch
	Peak Forward Current *1 I <sub>FP</sub> ±0.5		A/ch		
Transistor	Collector to Emitter Voltage	$V_{CEO}$	80		V
	Emitter to Collector Voltage	$V_{\text{ECO}}$		5	V
	Collector Current	Ic	3	30	mA/ch
	Power Dissipation Derating $\triangle P_{C}/^{\circ}C$ 1.2		mW/°C		
	Power Dissipation	Pc	1:	20	mW/ch
Isolation Voltage *2		BV	2 500		Vr.m.s.
Operating Ambient Temperature		T <sub>A</sub>	-55 to +100		°C
Storage Temperature		T <sub>stg</sub>	-55 to +150		°C

Notes: \*1. PW = 100  $\mu$ s, Duty Cycle = 1%

\*2. AC voltage for 1 minute at  $T_A = 25$ °C, RH = 60% between input and output.

Pins 1-2 shorted together, 3-4 shorted together (PS2805C-1).

Pins 1-8 shorted together, 9-16 shorted together (PS2805C-4).

# ELECTRICAL CHARACTERISTICS ( $T_A = 25$ °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V <sub>F</sub>	$I_F = \pm 5^{\circ} mA$		1.2	1.4	V
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		20		pF
Transistor	Collector to Emitter Dark Current	I <sub>CEO</sub>	V <sub>CE</sub> = 80 V, I <sub>F</sub> = 0 mA			100	nA
Coupled	Current Transfer Ratio $\left(I_{\text{C}}/I_{\text{F}}\right)^{*1}$	CTR	$I_F = \pm 5$ mA, $V_{CE} = 5$ V	50		400	%
	Collector Saturation Voltage	V <sub>CE (sat)</sub>	$I_F = \pm 10 \text{ mA}, I_C = 2 \text{ mA}$		0.13	0.3	V
	Isolation Resistance	R <sub>I-O</sub>	$V_{I-O} = 1.0 \text{ kV}_{DC}$	10 <sup>11</sup>			Ω
	Isolation Capacitance	C <sub>I-O</sub>	V = 0 V, f = 1.0 MHz		0.4		pF
	Rise Time *2	t <sub>r</sub>	$V_{CC}$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$		5		μS
	Fall Time *2	t <sub>f</sub>			7		
	Turn-on Time*2	t <sub>on</sub>			10		
	Turn-off Time*2	t <sub>off</sub>			7		

<R>

Notes: \*1. CTR rank

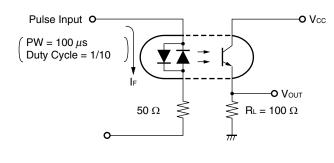
PS2805C-1

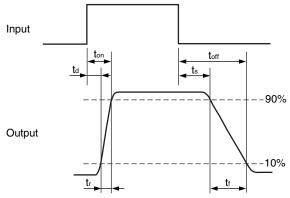
N: 50 to 400 (%) M: 100 to 400 (%)

PS2805C-4

N: 50 to 400 (%) M: 100 to 400 (%)

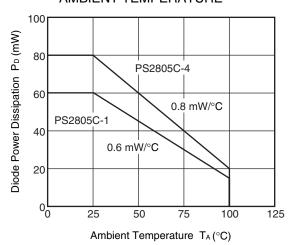
\*2. Test circuit for switching time



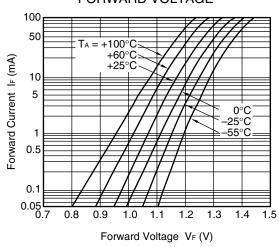


## <R> TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, unless otherwise specified)

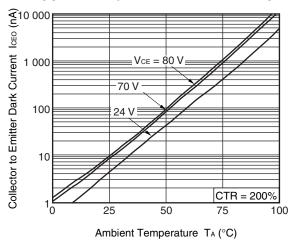
### DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE



#### FORWARD CURRENT vs. FORWARD VOLTAGE

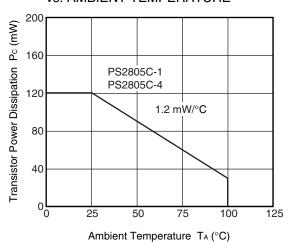


#### **COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE**

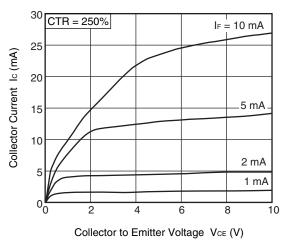


Remark The graphs indicate nominal characteristics.

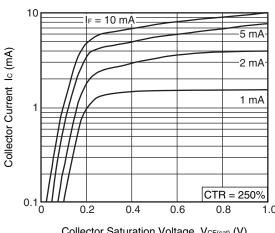
#### TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



#### COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

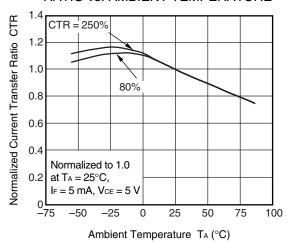


#### COLLECTOR CURRENT vs. **COLLECTOR SATURATION VOLTAGE**

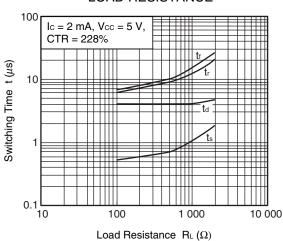


Collector Saturation Voltage VCE(sat) (V)

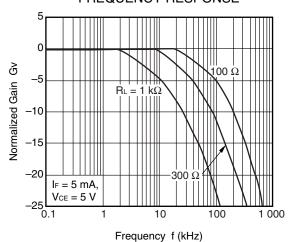
#### NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



### SWITCHING TIME vs. LOAD RESISTANCE

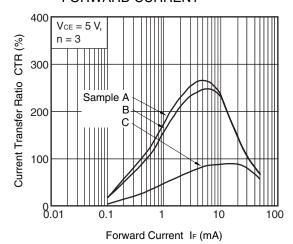


### FREQUENCY RESPONSE

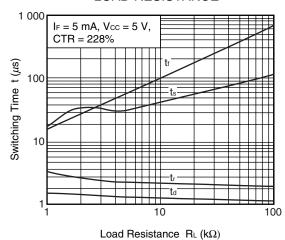


#### Remark The graphs indicate nominal characteristics.

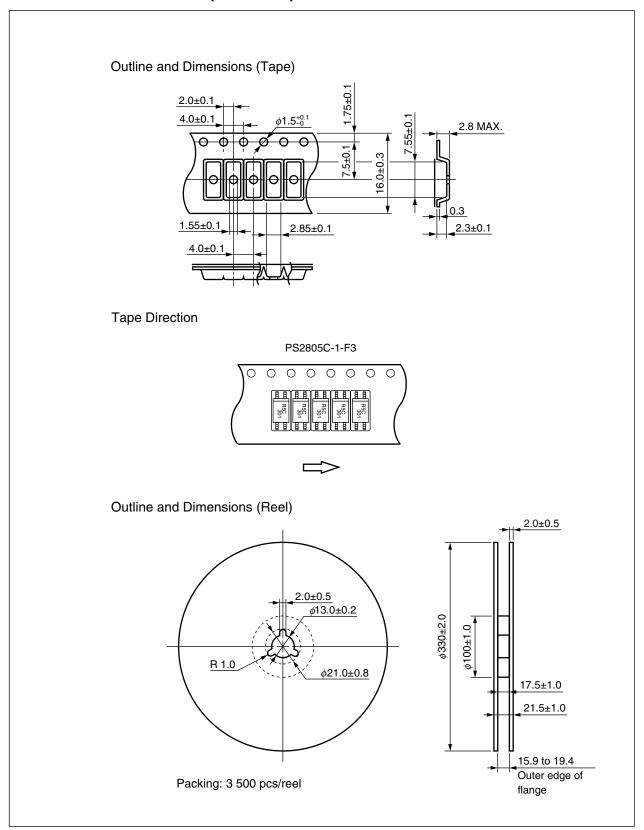
#### CURRENT TRANSFER RATIO vs. FORWARD CURRENT

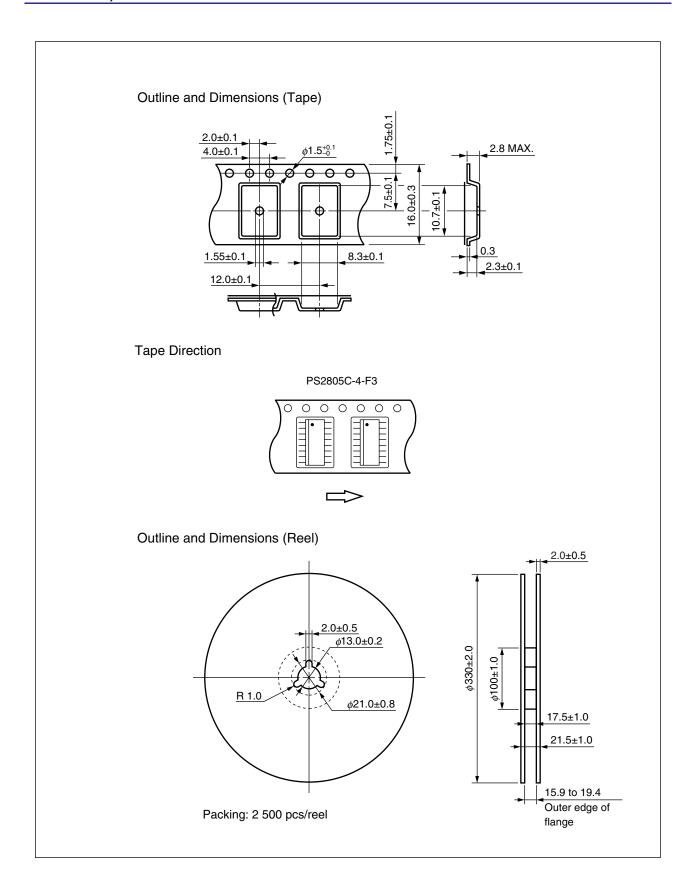


### SWITCHING TIME vs. LOAD RESISTANCE



## <R> TAPING SPECIFICATIONS (UNIT: mm)





#### <R> NOTES ON HANDLING

- 1. Recommended soldering conditions
  - (1) Infrared reflow soldering

Peak reflow temperature
 260°C or below (package surface temperature)

Time of peak reflow temperature 10 seconds or less
 Time of temperature higher than 220°C 60 seconds or less

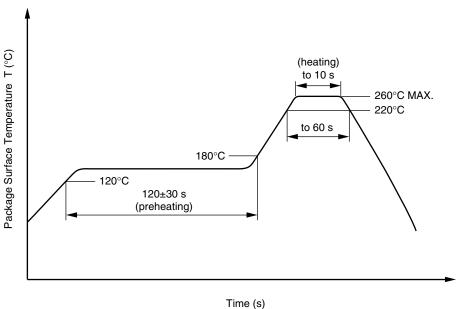
Time to preheat temperature from 120 to 180°C 120±30 s
 Number of reflows Three

Flux

Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is

recommended.)

#### Recommended Temperature Profile of Infrared Reflow



• Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

• Preheating conditions 120°C or below (package surface temperature)

Number of times
 One (Allowed to be dipped in solder including plastic mold portion.)

Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

(2) Wave soldering

• Peak Temperature (lead part temperature) 350°C or below

• Time (each pins) 3 seconds or less

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

- (4) Cautions
  - Fluxes Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.
- 2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collectoremitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. This tendency may sometimes be obvious, especially below  $I_F = 1 \text{ mA}$ .

Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

#### **USAGE CAUTIONS**

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.



## SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

	Parameter	Symbol	Spec.	Unit
	Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
<r> <r></r></r>	Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{\text{IORM}},  P_{\text{d}} < 5  \text{pC}$	Ulorm Upr	705 1 128	V <sub>peak</sub> V <sub>peak</sub>
	Test voltage (partial discharge test, procedure b for all devices) $U_{pr}=1.875\times U_{IORM},P_d<5\;pC$	Upr	1 322	$V_{peak}$
	Highest permissible overvoltage	Utr	6 000	$V_{peak}$
<r></r>	Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
/	Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
	Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
	Storage temperature range	T <sub>stg</sub>	-55 to +150	°C
	Operating temperature range	TA	-55 to +100	°C
	Isolation resistance, minimum value  VIO = 500 V dc at TA = 25°C  VIO = 500 V dc at TA MAX. at least 100°C	Ris MIN. Ris MIN.	10 <sup>12</sup> 10 <sup>11</sup>	Ω Ω
	Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve)			
	Package temperature	Tsi	150	°C
	Current (input current I <sub>F</sub> , Psi = 0)	lsi D	300	mA
	Power (output or total power dissipation)	Psi	500	mW
	Isolation resistance Vio = 500 V dc at TA = Tsi	Ris MIN.	10 <sup>9</sup>	Ω

# PS2805C-1, PS2805C-4 Data Sheet

		Description			
Rev.	Date	Page	Summary		
1.00	May 30, 2006	_	This data sheet was released as PN10611EJ01V0DS		
3.00	Jan 9, 2013	Throughout	Renesas format is applied to this data sheet.		
		p.1	The ordering number and safety standards are revised.		
		p.2	PHOTOCOUPLER CONSTRUCTION is added as each distance of this		
			device.		
		p.3	The explanation in MARKING EXAMPLE is revised.		
		p.4	ORDERING INFORMATION is modified with the revision of the safety		
			standards.		
		p.5	Turn-on Time $(t_{\text{on}})$ and Turn-off Time $(t_{\text{off}})$ are added to the table in		
			ELECTRICAL CHARACTERISTICS.		
		p.6	The graph of DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE		
			and TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE		
			are revised		
		p.7	The graph of LONG TERM CTR DEGRADATION is deleted.		
		p.8	PS2805C-1-F4 is deleted form Tape Direction image in TAPING		
			SPECIFICATIONS.		
		p.9	PS2805C-4-F4 is deleted form Tape Direction image in TAPING		
			SPECIFICATIONS.		
		p.10	The note about temperature condition of the recommended soldering		
			conditions is deleted.		
		p.12	The values in SPECIFICATION OF VDE MARKS LICENSE DOCUMENT are		
			changed as follows.		
			Test voltage is changed from the factor, 1.5, and the value, 1058, to 1.6		
			and 1128, respectively.		
			<ul> <li>Clearance distance is moved to PHOTOCOUPLER CONSTRUCTION with changing 5.0 (min.) to 4.5 (min.).</li> </ul>		

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